Middle Power LED Series Flip Chip Package

LM102A





LM102A opens up a new world of lighting design with its high output and small form factors

Features & Benefits

- Greater freedom of design with compact package size
- High degree of reliability with plastic-free structure
- Low thermal resistance
- High efficiency providing optimized solution
- Compact footprint (1.30 x 1.30 mm)



Applications

Indoor Lighting:

- Downlight
- LED Bulbs
- LED Tubes
- MR / PAR
- Ambient Light
- Ceiling Light

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1. Characteristics

a) Absolute Maximum Rating

Item	Symbol	Rating	Unit	Condition
Operating Temperature	Ta	-40 ~ +85	٥C	-
Storage Temperature	Tstg	-40 ~ +120	٥C	-
LED Junction Temperature	Tj	125	٥C	-
Forward Current	lF	250	mA	-
Assembly Process Temperature	-	260 <10	°C s	-
ESD (HBM)	-	±2	kV	-

b) Electro-optical Characteristics ($I_F = 150 \text{ mA}, T_s = 85 \text{ }^{\circ}\text{C}$)

Item	Unit	Rank	Bin	Min.	Тур.	Max.
Forward Voltage (V _F)	V	3F	-	-	5.89	-
Reverse Voltage (@ -10 μΑ)	V			-10.0	-	-
Color Rendering Index (R_a)	-	8		80	-	-
Special CRI (R9)	-			0	-	-
Thermal Resistance (junction to chip point)	KW			-	2	-
Beam Angle	0			-	145	-

Note:

Samsung maintains measurement tolerance of: forward voltage = ± 0.1 V, luminous flux = ± 5 %, CRI = ± 3 , R9 = ± 6.5

c) Luminous Flux Characteristics	(I _F = 150 mA, T _s = 85 °C)
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			S	A	S	В	S	C	S	D	S	Ε	S	F
ltem	CRI	Nominal CCT (K)	Min.	Max.										
			79	87	87	95	95	103	103	111	111	119	119	127
		3000												
		3500												
	70	4000												
	70	5000												
		5700												
		6500												
		2700												
Luminous		3000												
Flux (Φ _v)		3500												
	80	4000												
		5000												
		5700												
		6500												
		2700												
	90	3000												
		3500												

Note:

- 1) The LM102A is tested in pulsed condition at rated test current (10 ms pulse width)
- 2) Samsung maintains measurement tolerance of: luminous flux = $\pm 5 \%$

2. Product Code Information ($I_F = 150 \text{ mA}, T_s = 85 \text{ °C}$)

1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18
S																	

Digit	PKG Information	Code	Specification
1 2 3	Samsung Chip	SCS	
		7	Min. 70
4	CRI	8	Min. 80
		9	Min. 90
		w	2700
		v	3000
		U	3500
5	CCT (K)	т	4000
		R	5000
		Q	5700
		Р	6500
6	Chip Shape	т	Square
789	Chip Size (µm)	93H	930x930x170µm
10 11 12	Product Purpose	PL2	PoC for Lighting
		w	2700K
		v	3000K
		U	3500K
13	CCT (K)	т	4000K
		R	5000K
		Q	5700K
		Р	6500K
14	MacAdam Step		Single Bin for MacAdam 5-stepL(MacAdam 5-step Bin)Single Bin for MacAdam 3-stepU(MacAdam 3-step Bin)
15 16	Luminous Flux (Im)	S0	Bin Code: SA, SB, SC, SD, SE, SF
17 18	Forward Voltage (V)	3F	39 5.6~5.9 5.6~6.2 Bin Code: 9F 5.9~6.2

a) Luminous Flux Bins $(I_F = 150 \text{ mA}, T_s = 85 \text{ }^{\circ}\text{C})$

CRI (R₂) Min.	Nominal CCT (K)	Product Code	Flux Bin	Flux Range (Φ _v , Im)
	3000		SD	103 ~ 111
	3000	SCS7VT93HPL2V☆S03F	SE	111 ~ 119
	2500		SD	103 ~ 111
	3500	SCS7UT93HPL2U☆S03F	SE	111 ~ 119
	4000	SCS7TT93HPL2T☆S03F	SE	111 ~ 119
70		3C371193HPL21%303F	SF	119 ~ 127
70		SCS7RT93HPL2R☆S03F	SE	111 ~ 119
	5000	3U3/KT93HPL2K≋SU3F	SF	119 ~ 127
	5700	SCS7QT93HPL2Q☆S03F	SE	111 ~ 119
	5700	3037Q193HFL2Q×303F	SF	119 ~ 127
	6500	SCS7PT93HPL2P☆S03F	SE	111 ~ 119
	0500	303/F1930FL2PX303F	SF	119 ~ 127

a) Luminous Flux Bins $(I_F = 150 \text{ mA}, T_s = 85 \text{ °C})$

CRI (R₂) Min.	Nominal CCT (K)	Product Code	Flux Bin	Flux Range (Φ _v , Im)
	2700	SCS8WT93HPL2W☆S03F	SC	95 ~ 103
	2700	202900 1 23ULT70 × 202L	SD	103 ~ 111
	3000		SC	95 ~ 103
	3000	SCS8VT93HPL2V☆S03F	SD	103 ~ 111
	2500		SD	103 ~ 111
	3500	SCS8UT93HPL2U☆S03F	SE	111 ~ 119
80	4000		SD	103 ~ 111
80	4000	SCS8TT93HPL2T☆S03F	SE	111 ~ 119
	5000		SE	111 ~ 119
	5000	SCS8RT93HPL2R☆S03F	SF	119 ~ 127
	5700	SCS8QT93HPL2Q☆S03F	SD	103 ~ 111
	5700	3030Q133NPL2Q3303F	SE	111 ~ 119
	6500		SD	103 ~ 111
	6500	SCS8PT93HPL2P☆S03F	SE	111 ~ 119

a) Luminous Flux Bins $(I_F = 150 \text{ mA}, T_s = 85 \text{ }^{\circ}\text{C})$

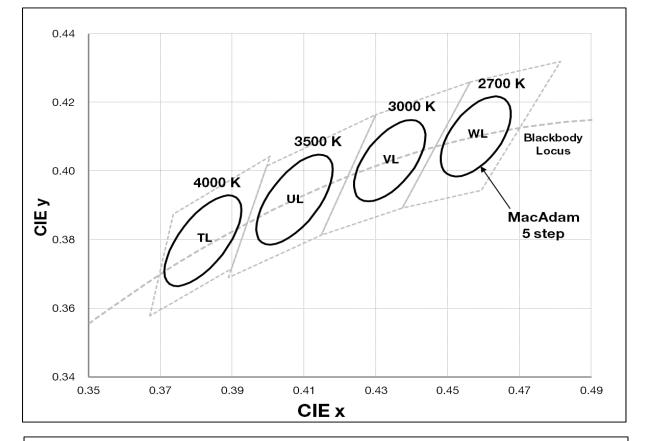
CRI (R₃) Min.	Nominal CCT (K)	Product Code	Flux Bin	Flux Range (Φ _v , Im)
	2700	SCS9WT93HPL2W☆S03F	SA	79 ~ 87
	2700	GGGSWTSSTILLZWAGGST	SB	87 ~ 95
90	3000	SCS9VT93HPL2V☆S03F	SA	79 ~ 87
90	3000	3039V133HFL2V×303F	SB	87 ~ 95
	3500	SCS9UT93HPL2U☆S03F	SA	79 ~ 87
		303901930FL20%303F	SB	87 ~ 95

b) Color Bins $(I_F = 150 \text{ mA}, T_s = 85 \text{ }^{\circ}\text{C})$

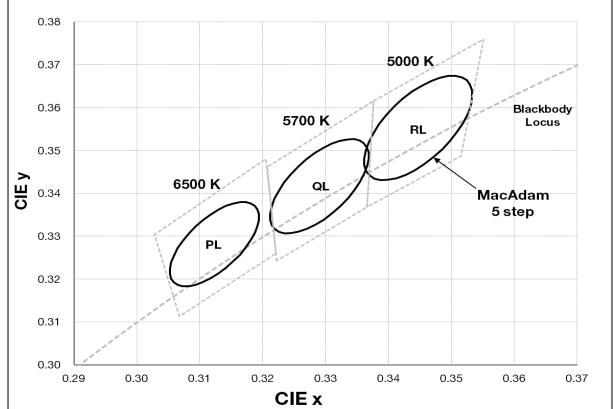
CRI	Nominal CCT	Product Code	Color Rank	Chromaticity Bins
Min.	(K)		VL	VL
	3000	SCS7VT93HPL2V☆S03F	VU	VU
			UL	UL
	3500	SCS7UT93HPL2U☆S03F	UU	UU
			TL	TL
	4000	SCS7TT93HPL2T☆S03F	TU	TU
70			RL	RL
	5000	SCS7RT93HPL2R [☆] S03F	RU	RU
			QL	QL
	5700	SCS7QT93HPL2Q ¹ / ₂ S03F	QU	QU
			PL	PL
	6500	SCS7PT93HPL2P ¹ S03F	PU	PU
			WL	WL
	2700	SCS8WT93HPL2W☆S03F	WU	WU
			VL	VL
	3000	SCS8VT93HPL2V ¹ S03F	VU	VU
			UL	UL
	3500	SCS8UT93HPL2U%S03F	UU	UU
			TL	TL
80	4000	SCS8TT93HPL2T☆S03F		TU
			RL	RL
	5000	SCS8RT93HPL2R ¹ S03F	RU	RU
			QL	QL
	5700	SCS8QT93HPL2Q%S03F	QU	QU
			PL	PL
	6500	SCS8PT93HPL2P ¹ S03F	PU	PU
	2700	SCS8WT93HPL2W☆S03F	WL	WL
			VL	VL
90	3000	SCS8VT93HPL2V☆S03F	VL	VL
	3500	SCS8UT93HPL2U☆S03F	UL	UL
			UU	UU

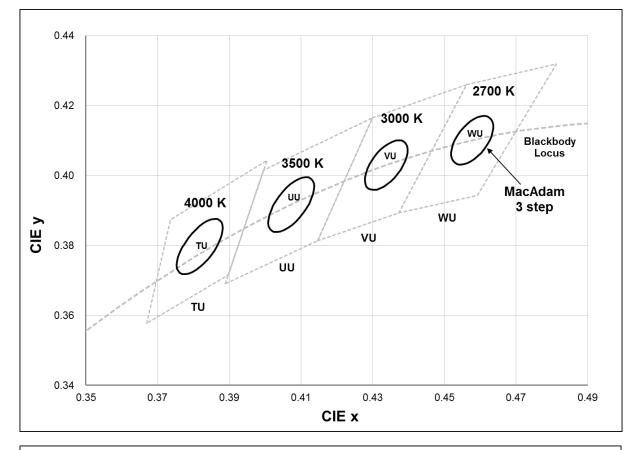
c) Voltage Bins ($I_F = 150 \text{ mA}, T_s = 85 \text{ }^{\circ}\text{C}$)

Nominal CCT	Product Code	Voltage Rank	Voltage Bin	Voltage Range
		3F	39	5.6 ~ 5.9
		3F ·	9F	5.9 ~ 6.2

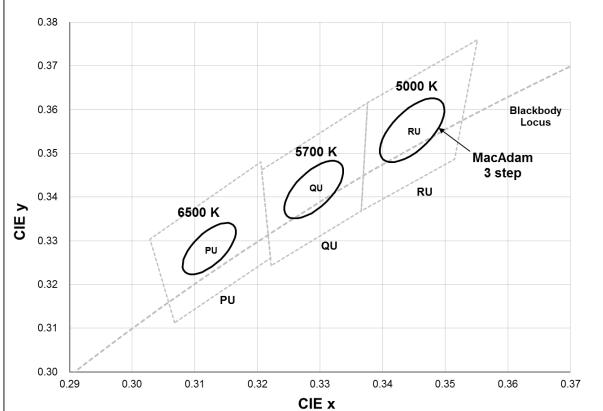


d) Chromaticity Region & Coordinates (I_F = 150 mA, T_s = 85 °C) : "L" (Full bin for MacAdam 5-step)

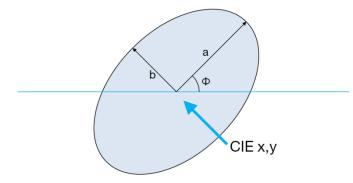




d) Chromaticity Region & Coordinates (I_F = 150 mA, T_s = 85 °C) : "U" (Single for MacAdam 3-step)



d) Chromaticity Region & Coordinates (I_F = 150 mA, T_s = 85 °C)

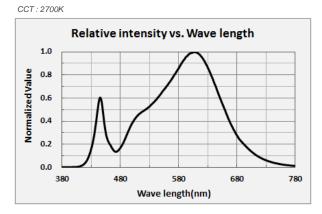


	ССТ	Cento	er point	Major-axis	Minor-axis	Rotation
	(K)	CIE x	CIE y	а	b	Φ
3 step (U code)	2700	0.4578	0.4101	0.0081	0.0042	53.70
	3000	0.4338	0.4030	0.0083	0.0041	53.22
	3500	0.4073	0.3917	0.0093	0.0041	54.00
	4000	0.3818	0.3797	0.0094	0.0040	53.72
	5000	0.3447	0.3553	0.0082	0.0035	59.62
	5700	0.3287	0.3417	0.0075	0.0032	59.10
	6500	0.3123	0.3282	0.0067	0.0029	58.57
	2700	0.4578	0.4101	0.0135	0.0070	53.70
5 step (L code)	3000	0.4338	0.4030	0.0138	0.0068	53.22
	3500	0.4073	0.3917	0.0155	0.0068	54.00
	4000	0.3818	0.3797	0.0157	0.0067	53.72
	5000	0.3447	0.3553	0.0137	0.0058	59.62
	5700	0.3287	0.3417	0.0125	0.0053	59.10
	6500	0.3123	0.3282	0.0112	0.0048	58.57

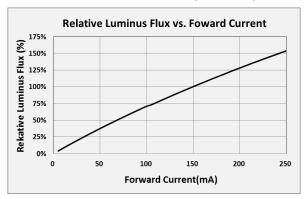
Note: Samsung maintains measurement tolerance of: Cx, Cy = ± 0.005

3. Typical Characteristics Graphs

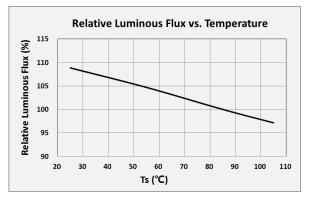
a) Spectrum Distribution ($I_F = 150 \text{ mA}, T_s = 25 \text{ °C}$)

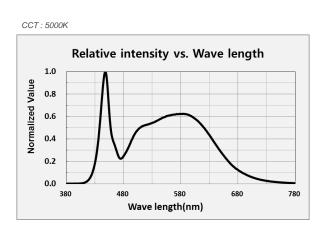


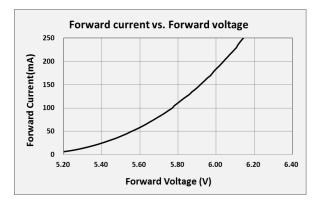
b) Forward Current Characteristics (T_s = 25 °C)

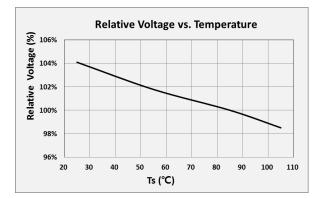


c) Temperature Characteristics (I_F = 150 mA)



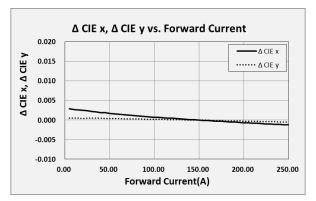




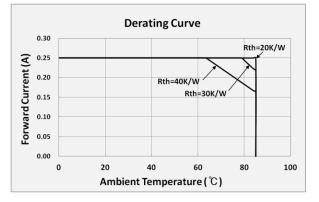


d) Color Shift Characteristics

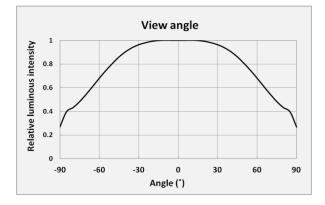
T_s = 25 °C

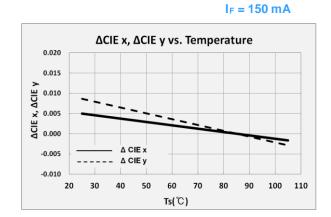


e) Derating Curve



f) Beam Angle Characteristics $(I_F = 150 \text{ mA})$

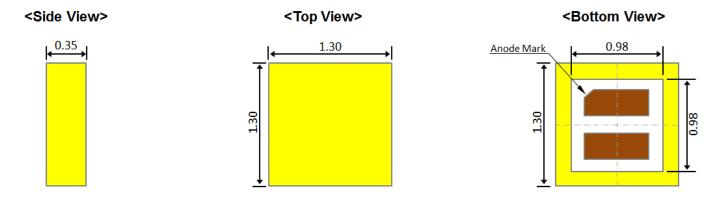




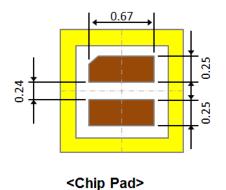
17

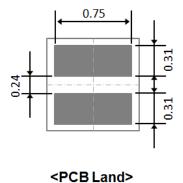
4. Outline Drawing & Dimension

- 1. Tolerance is ±0.10 mm
- 2. Do not place LEDs with pressure



<Recommended Land Pattern>



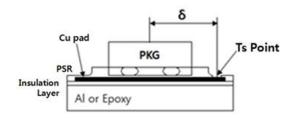


Ts Point & Measurement Method:

Measure nearest point from the center of LED chip (δ) as shown below.

Distance between chip center and T_s point (δ) = 3.5 mm

 T_j = T_s + Power x Thermal resistance at $T_s \ (R_{j\text{-s}})$



Precautions:

- 1) This LED chip PKG does not contain built-in ESD protection device.
- Pressure on the LEDs will influence to the reliability of the LEDs. Precautions should be taken to avoid strong pressure on the LEDs. Do not put stress on the LEDs during heating.
- Re-soldering should not be done after the LEDs have been soldered. If re-soldering is unavoidable, LED's characteristics should be carefully checked before and after such repair.
- 4) Do not stack assembled PCBs together. Since materials of LEDs is soft, abrasion between two PCB assembled with LED might cause catastrophic failure of the LEDs.

5. Reliability Test Items & Conditions

a) Test Items

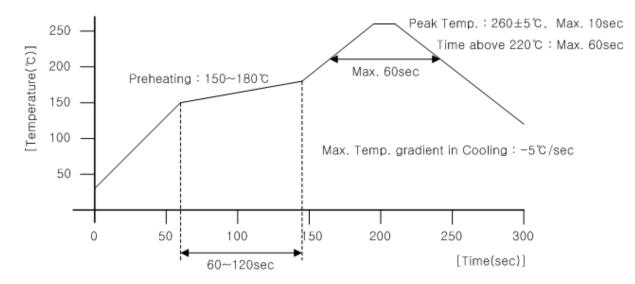
Test Item	Test Condition	Test Hour / Cycle	Sample Size
Room Temperature Life Test	25 °C, DC 250 mA	1000 h	22
High Temperature Life Test	85 °C, DC 250 mA	1000 h	22
High Temperature Humidity Life Test	85 °C, 85 % RH, DC 250 mA	1000 h	22
Low Temperature Life Test	-40 °C, DC 250 mA	1000 h	22
Powered Temperature Cycle Test	-45 °C / 20 min ↔ 85 °C / 20 min, sweep 100 min cycle on/off: each 5 min, DC 250 mA	100 cycles	22
Thermal Shock	-45 °C / 15 min ↔ 125 °C / 15 min → Hot plate 180 °C	800 cycles	100
High Temperature Storage	120 °C	1000 h	11
Low Temperature Storage	-40 °C	1000 h	11
ESD (HBM)	R1: 10 ΜΩ R2: 1.5 KΩ C: 100 pF W: ±5 kV	5 times	5
Vibration Test	20~2000~20 Hz, 200 m/s ² , sweep 4 min X, Y, Z 3 direction, each 1 cycle	4 cycles	11
Mechanical Shock Test	1500 g, 0.5 ms	5 cycles	11

b) Criteria for Judging the Damage

Item	Symbol	Test Condition	Limit		
nem	Cymbol	(T _s = 25 °C)	Min	Max	
Forward Voltage	VF	I _F = 250 mA	Init. Value * 0.9	Init. Value * 1.1	
Luminous Flux	Φv	I _F = 250 mA	Init. Value * 0.7	Init. Value * 1.1	

6. Soldering Conditions

a) Reflow Conditions (Pb free)



Reflow frequency: 2 times max.

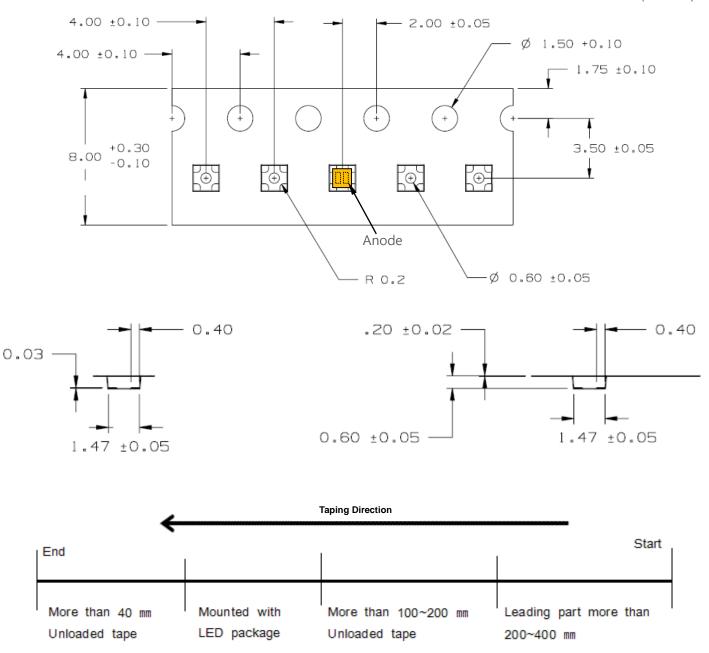
b) Manual Soldering Conditions

Not more than 5 seconds @ max. 300 °C, under soldering iron.

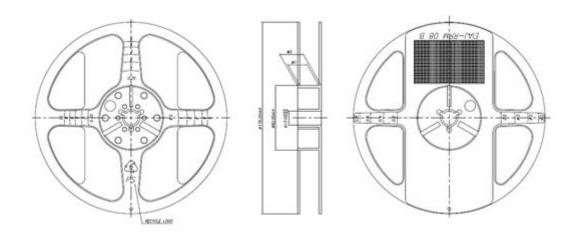
7. Tape & Reel

a) Taping Dimension

(unit: mm)



b) Reel Dimension



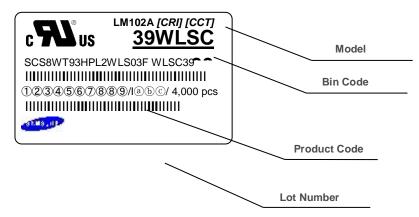
Width	W7	W2	
8mm	9 ±0.3	11.9 ±1.0	

Notes:

- 1) Quantity: The quantity/reel is 4,000 pcs
- 2) Cumulative Tolerance: Cumulative tolerance / 10 pitches is ±0.2 mm
- 3) Packaging: P/N, Manufacturing data code no. and quantity are indicated on the aluminum packing bag

8. Label Structure

a) Label Structure



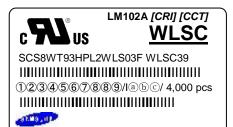
Note: Denoted product code and bin code above is only an example

Rank Code:

- (a) (b): Chromaticity bin (refer to page 10-11)
- © d: Luminous Flux bin (refer to page 7)
- (e)(f): Forward Voltage bin (refer to page 12)

b) Lot Number

The lot number is composed of the following characters:



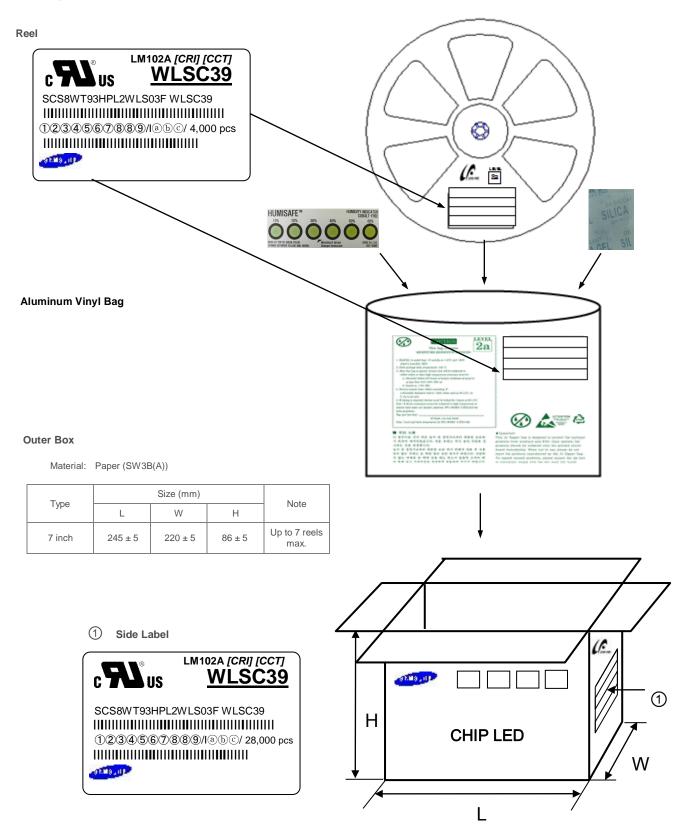
(123456789/labc /4,000 pcs

- (1)2 : Production site (G3: Shenzhen China, G4: Guangzhou China, GB: Nanchang China)
- (3) : Product state (A: Normal, B: Bulk, C: First Production, R: Reproduction, S: Sample)
- (4) : Year (Y: 2014, Z: 2015, A: 2016 ...)
- (5) : Month (1~9, A, B, C)
- 6 : Day (1~9, A, B~V)

- (7)(8)(9) : Product serial number (001 ~ 999)
- (a)b)C) : Reel number (001 ~ 999)

9. Packing Structure

a) Packing Process

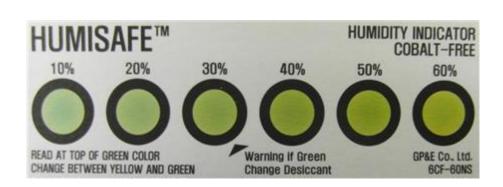


b) Aluminum Vinyl Packing Bag



c) Silica Gel & Humidity Indicator Card inside Aluminum Vinyl Bag





10. Precautions in Handling & Use

- 1) For over-current-proof function, customers are recommended to apply resistors to prevent sudden change of the current caused by slight shift of the voltage.
- 2) This device should not be used in any type of fluid such as water, oil, organic solvent, etc. When washing is required, IPA is recommended to use.
- 3) When the LEDs illuminate, operating current should be decided after considering the ambient maximum temperature.
- 4) LEDs must be stored in a clean environment. If the LEDs are to be stored for three months or more after being shipped from Samsung, they should be packed by a sealed container with nitrogen gas injected (shelf life of sealed bags: 12 months, temperature ~40 °C, ~90 % RH).
- After storage bag is opened, device subjected to soldering, solder reflow, or other high temperature processes must be:
 a. Mounted within 672 hours (28 days) at an assembly line with a condition of no more than 30 °C / 60 % RH, or
 - b. Stored at <10 % RH
- 6) Repack unused products with anti-moisture packing, fold to close any opening and then store in a dry place.
- 7) Devices require baking before mounting, if humidity card reading is >65 % at 23 ± 5 °C.
- 8) Devices must be baked for 1 hour at 60 ± 5 °C, if baking is required.
- 9) The LEDs are sensitive to the static electricity and surge. It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs. If voltage exceeding the absolute maximum rating is applied to LEDs, it may cause damage or even destruction to LED devices. Damaged LEDs may show some unusual characteristics such as increase in leak current, lowered turn-on voltage, or abnormal lighting of LEDs at low current.
- 10) VoCs (Volatile Organic Compounds) can be generated from adhesives, flux, hardener or organic additives used in luminaires (fixtures). LED silicone encapsulant is permeable to those chemicals and they may lead to a discoloration of encapsulant when they exposed to heat or light. This phenomenon can cause a significant loss of light emitted (output) from the luminaires. In order to prevent these problems, we recommend users to know the physical properties of materials used in luminaires and they must be carefully selected.
- 11) Risk of sulfurization (or tarnishing)

The LED from Samsung does not use a silver-plated lead frame but if the LED is attached in silver-plated substrate, the surface color of substrate may change to black (or dark colored) when it is exposed to sulfur (S), chlorine (CI) or other halogen compound. Sulfurization of substrate may cause intensity degradation, change of chromaticity coordinates and, in extreme cases, open circuit, It requires caution. Due to possible sulfurization of substrate, LED should not be used and stored together with oxidizing substances made of materials such as rubber, plain paper, lead solder cream, etc.

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